L Number	Hite	Search Text	DB	Time stamp
- Humber	4	'gate oxide' and 'in-situ steam	USPAT;	2003/08/22 07:29
	•	generation'	US-PGPUB;	2000, 00, 22 0 0 0 0
		, gonous	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	7	@ad<=20020219 and 'ONO' and 'in-situ steam	USPAT;	2003/08/22 07:29
		generation' or 'ISSG'	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
		0. 14. 00000010 and 10001 and 170001	IBM_TDB USPAT;	2002/05/24 08:28
-	1	@ad<=20020219 and 'ONO' and 'ISSG'	US-PGPUB;	2002/03/24 08.28
			EPO; JPO;	
	ļ		DERWENT;	
			IBM TDB	
_	10	@ad<=20020219 and 'in-situ steam	USPAT;	2002/05/24 08:32
		generation' or 'ISSG'	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	52	(438/954).CCLS.	USPAT;	2002/05/24 13:24
			US-PGPUB;	•
1			EPO; JPO; DERWENT;	
			IBM TDB	
_	245	(438/593).ccls. and @ad<=20020119	USPAT;	2002/05/24 13:26
	243	(100,000,0010. and (dd. 2002011)	US-PGPUB;	
			EPO; JPO;	
1			DERWENT;	
1			IBM_TDB	
-	627	(438/770).ccls. and @ad<=20020119	USPAT;	2002/05/24 13:31
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	481	(438/264).ccls. and @ad<=20020119	IBM_TDB USPAT;	2002/05/24 13:27
-	401	(436/264).CCIS. and Gad\-20020119	US-PGPUB;	2002/03/24 13:21
j	1		EPO; JPO;	
			DERWENT;	
		·	IBM TDB	
-	208	(438/594).ccls. and @ad<=20020119	USPAT;	2002/05/24 13:27
1	<u>n</u> .		US-PGPUB;	
			EPO; JPO;	
1			DERWENT;	
		(430/375) cold and 0ad<-20020110	IBM_TDB	2002/05/24 13:28
-	518	(438/275).ccls. and @ad<=20020119	USPAT; US-PGPUB;	2002/03/24 13.20
	₩.	,	EPO; JPO;	
	<u> </u>		DERWENT;	
	<b>BEST AVAIL</b> ABI		IBM TDB	
-	323	(438/199).ccls. and @ad<=20020119	USPĀT;	2002/05/24 13:28
	<b>*</b>		US-PGPUB;	
	<b>a</b>		EPO; JPO;	
			DERWENT;	
1		(420/477)1	IBM_TDB USPAT;	2002/05/24 13:28
-	91	(438/477).ccls. and @ad<=20020119	US-PGPUB;	2002/03/24 13:20
1	<b>~</b>		EPO; JPO;	
1	444		DERWENT;	
			IBM TDB	
_	77	(438/216).ccls. and @ad<=20020119	USPĀT;	2002/05/24 13:28
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	0000/05/04 10 00
-	577	(438/287).ccls. and @ad<=20020119	USPAT;	2002/05/24 13:29
			US-PGPUB; EPO; JPO;	
			DERWENT;	
			IBM TDB	
	L		1 22.1 272	.1

Search History 8/22/03 11:35:03 AM Page 1 C:\APPS\EAST\Workspaces\FET MOS IGFET HEMT\10079472 gate oxide with ISSP process.wsp

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-	166	(438/783).ccls. and @ad<=20020119	USPAT;	2002/05/24 13:29
			US-PGPUB;	
			EPO; JPO;	ļ
			DERWENT;	
			IBM_TDB	
-	8	'gate oxide' and 'in-situ steam	USPAT;	2002/10/16 10:36
		generation' or 'LP-RTP'	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	:
_	2	("5324675").PN.	IBM_TDB USPAT;	2002/10/16 10:11
	_	( JJ240/J ) . EN .	US-PGPUB;	2002/10/10 10.11
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	1	'thin film transistor' and 'gate oxide'	USPĀT;	2002/10/16 10:49
		and 'in-situ steam generation' or 'LP-RTP'	US-PGPUB;	
			EPO; JPO;	
	1		DERWENT;	
			IBM_TDB	
-	27216	@ad<=20020219 and 'TFT'	USPAT;	2002/10/16 10:35
	1		US-PGPUB;	
			EPO; JPO; DERWENT;	
			IBM TDB	
_	٥ ا	(@ad<=20020219 and 'TFT') and 'oxide' and	USPAT;	2002/10/16 10:38
	1	'ISSG'	US-PGPUB;	2002/10/10 10.30
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
] -	0	(@ad<=20020219 and 'TFT') and 'oxide' and	USPAT;	2002/10/16 10:38
		'in-situ steam generation'	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	0	(caa loolollo ana lii ) ana onlao ana	USPAT;	2002/10/16 10:39
		'LP-RTP'	US-PGPUB;	
			EPO; JPO; DERWENT;	l
			IBM TDB	
_	226	(@ad<=20020219 and 'TFT') and 'floating	USPAT;	2002/10/16 10:39
		gate'	US-PGPUB;	
	6		EPO; JPO;	
	<b>A</b> CO 169		DERWENT;	
	ر ا		IBM_TDB	
-	O 169	(@ad<=20020219 and 'TFT') and 'oxide' and	USPAT;	2002/10/16 10:55
	LLi	'floating gate'	US-PGPUB;	
			EPO; JPO;	
	<b>m</b>		DERWENT;	
]_	BEST AVAILABLE	'tft' and 'in-situ steam generation' or	IBM_TDB USPAT;	2002/10/16 11:12
	⁺ ليج ا	'LP-RTP'	US-PGPUB;	2002/10/10 11:12
	<b>&amp;</b>		EPO; JPO;	
1	>		DERWENT;	
	A		IBM TDB	
-	0	'tft' and 'in-situ steam generation'	USPAT;	2002/10/16 10:51
	- TO		US-PGPUB;	
	111		EPO; JPO;	
	<b>6</b>		DERWENT;	
		/0-d<-0000010	IBM_TDB	0000/10/16 11 0:
-	64	(@ad<=20020219 and 'TFT') and 'oxide	USPAT;	2002/10/16 11:04
[ · · ]		layer' and 'floating gate'	US-PGPUB; EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	571	(438/149).CCLS.	USPAT;	2002/10/16 11:05
			US-PGPUB;	
	ļ		EPO; JPO;	
			DERWENT;	
			IBM_TDB	L

4	,
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			-	
-	11	@ad<=20020214 and (438/149).ccls. and	USPAT;	2002/10/16 11:06
		'floating gate'	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	3585	((438/294) or (438/954) or (438/593-594)	USPAT;	2002/10/17 09:50
_	3363	or (438/770) or (438/264) or (438/275) or	US-PGPUB;	2002/10/17 03:30
			EPO; JPO;	
		(438/199) or (438/477) or (438/216) or	DERWENT;	
		(438/287) or (438/783)).CCLS.	1	
	1.5	0 14 00000010 1 170001	IBM_TDB	2002/02/26 11.57
-	15	@ad<=20020219 and 'ISSG'	USPAT;	2003/02/26 11:57
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	29	@ad<=20020219 and 'ONO' and 'in-situ steam	USPAT;	2003/02/26 12:54
		generation' or 'ISSG'	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	27	@ad<=20020219 and 'ISSG'	USPĀT;	2003/02/26 12:07
ļ			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
	2	@ad<=20020219 and 'low pressure rapid	USPAT;	2003/02/26 12:17
-			US-PGPUB;	2003/02/20 12.17
		thermal process'	EPO; JPO;	
	į	,	1	
			DERWENT;	
		0 1. 0000010 1 1 1 1 1 1 1 1 1 1 1 1 1 1	IBM_TDB	2002/02/27 07:12
1 -	416	@ad<=20020219 and 'TFT' and 'ONO'	USPAT;	2003/02/27 07:12
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	0		USPAT;	2003/02/27 07:12
İ		'ISSG'	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
1			IBM_TDB	
	0	@ad<=20020219 and 'TFT' and 'ISSG'	USPAT;	2003/02/27 07:13
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	·
-	71	@ad<=20020219 and 'in-situ steam	USPĀT;	2003/08/22 08:16
		generation' or 'ISSG'	US-PGPUB;	
			EPO; JPO;	
1			DERWENT;	
			IBM TDB	
_	2	("6525384").PN.	USPAT;	2003/08/22 09:48
		( 3323301 / 12111	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
1			IBM TDB	
	<u> </u>		TOM IND	1